NSN 5961-01-066-4960

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-066-4960 **Inclosure Material:** Metal **Overall Length:** Between 0.215 inches and 0.240 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.187 inches **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 400.0 reverse voltage, peak **Current Rating Per Characteristic:** 10.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 14.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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